

# **Pre-Lab 12:**

## **MOSFET Amplifier**

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## Calculation

Choose  $\hat{V}_0 = 2.3V$ ,  $R_i = 11k\Omega$

$$I_X \geq \frac{2.3}{100} = 23mA \Rightarrow I_X = 40mA$$

$$I_{D2} = I_{D3} = I_X = 45mA$$

$$I_{D2} = \frac{\beta}{2} V_{ov}^2 \Rightarrow 45mA = \frac{95.464 mA/V^2}{2} V_{ov2}^2$$

$$\Rightarrow V_{ov2} = 0.971V = V_{ov3}$$

$$g_{m2} = \beta V_{ov2} = 95.464 \cdot 0.971 = 92.69 mA/V$$

$$A_{v2} = \frac{R_L}{\frac{1}{g_{m2}} + R_L} = \frac{100}{\frac{1}{92.69} + 100} = 1$$

$$\hat{V}_d = \frac{\hat{V}_0}{A_{v2}} = \frac{2.3}{1} = 2.3V$$

Choose  $V_{RX} = 0.55V$ ,  $V_{RS} = 0.6V$

$$V_{DD} + V_{SS} - \hat{V}_d - V_{RS} - V_{ov1} \geq V_{RD} \geq V_{RX} + V_{ov3} + \hat{V}_0 + V_{th} + V_{ov2}$$

$$5 + 5 - 2.3 - 0.55 - \frac{2 \cdot V_{RD}}{50} \cdot 1 \geq V_{RD} \geq 0.6 + 0.971 + 2.3 + 2 + 0.971$$

$$6.875 \geq V_{RD} \geq 6.844 \Rightarrow V_{RD} = 6.875V$$

$$V_{ov1} = \frac{2 \cdot 6.875}{50} = 0.275V$$

$$I_{D1} = \frac{\beta}{2} V_{ov1}^2 = \frac{1.1}{2} \cdot 0.275^2 = 0.042mA = 42\mu A$$

$$R_D = \frac{V_{RD}}{I_{D1}} = \frac{6.875}{42\mu A} = 163.69k\Omega \quad R_X = \frac{0.55V}{45mA} = 12\Omega$$

$$R_S = \frac{0.6V}{45mA} = 13\Omega$$

$$V_{RG2} = V_{RS} + |V_t| + V_{ov} = 0.6V + 1.5 + 0.275 = 2.375V$$



$$\begin{cases} V_{RG2} = 10 \cdot \frac{R_{G2}}{R_{G1} + R_{G2}} = 2.375V \\ R_1 = 11k = \frac{R_{G1} \cdot R_{G2}}{R_{G1} + R_{G2}} \end{cases} \Rightarrow \underline{R_{G1} = 46315.8\Omega, R_{G2} = 14426.2\Omega}$$

$$V_{RG4} = 0.55 + 2 + 0.971 = 3.521V$$

$$V_{RG4} = 3.521 = 10 \cdot \frac{R_{G4}}{R_{G3} + R_{G4}}$$

$$\Rightarrow \frac{352.1}{1000} = \frac{R_{G4}}{R_{G3} + R_{G4}} \Rightarrow \underline{R_{G4} = 352.1\Omega} \quad \underline{R_{G3} = 647.9\Omega}$$



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## Simulation

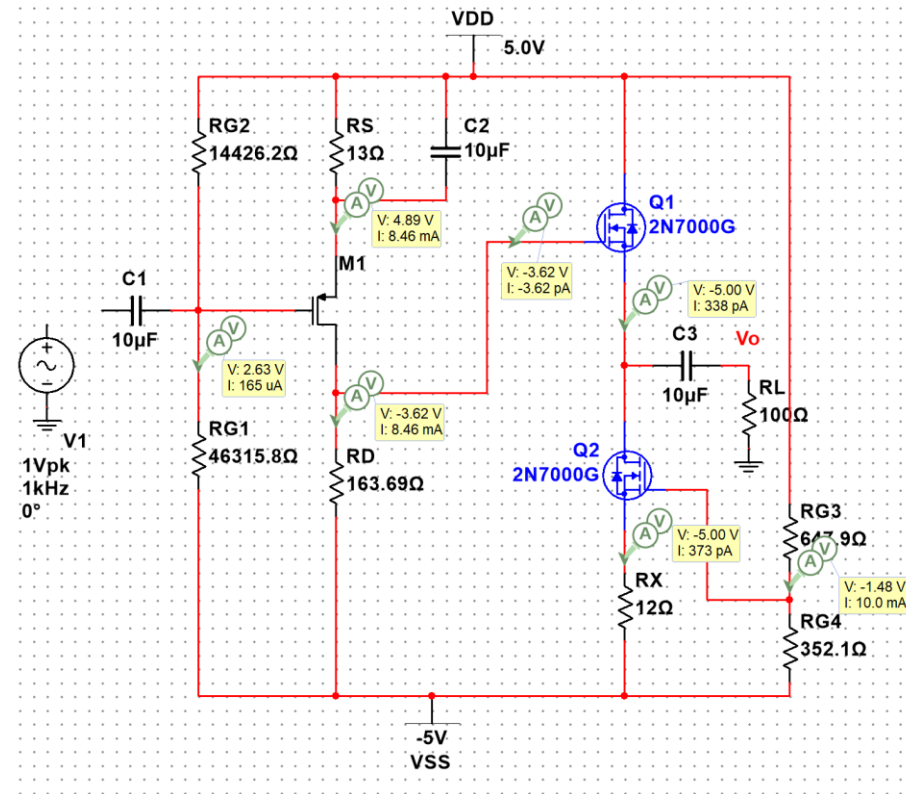
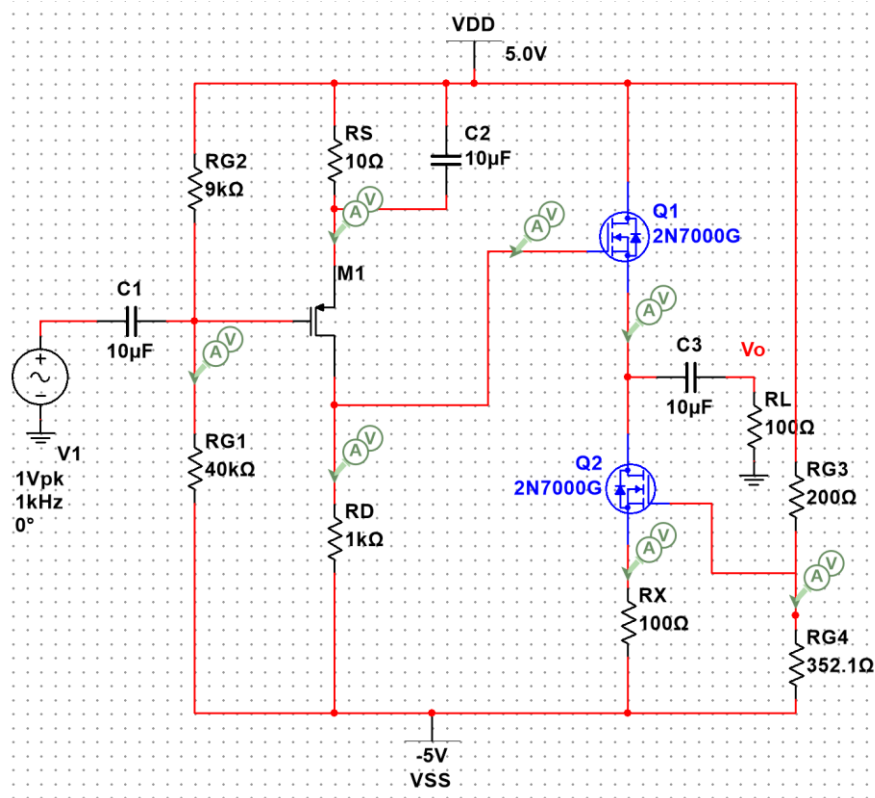


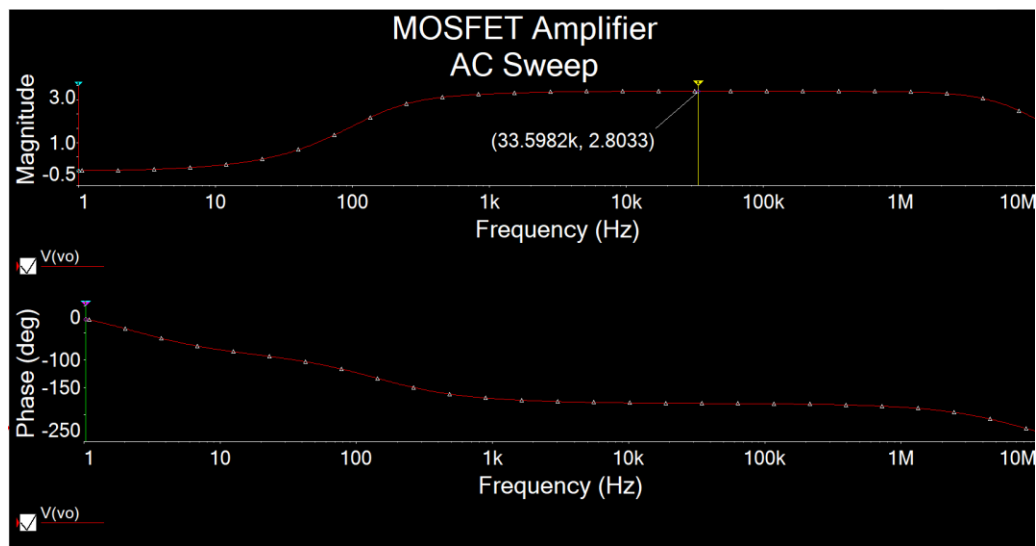
Figure 1: DC Solution for MOSFET amplifier ▲

$V_{RG1} = 7.63V$	$V_{RS} = 0.11V$	$I_{D1} = 8.46mA$
$V_{RG2} = 2.37V$	$V_{RD} = 1.38V$	$I_{D2} = 338pA$
$V_{RG3} = 6.48V$		$I_{D3} = 373pA$
$V_{RG4} = 3.52V$		

For this circuit, I got a gain of 0. So I rework the circuit.



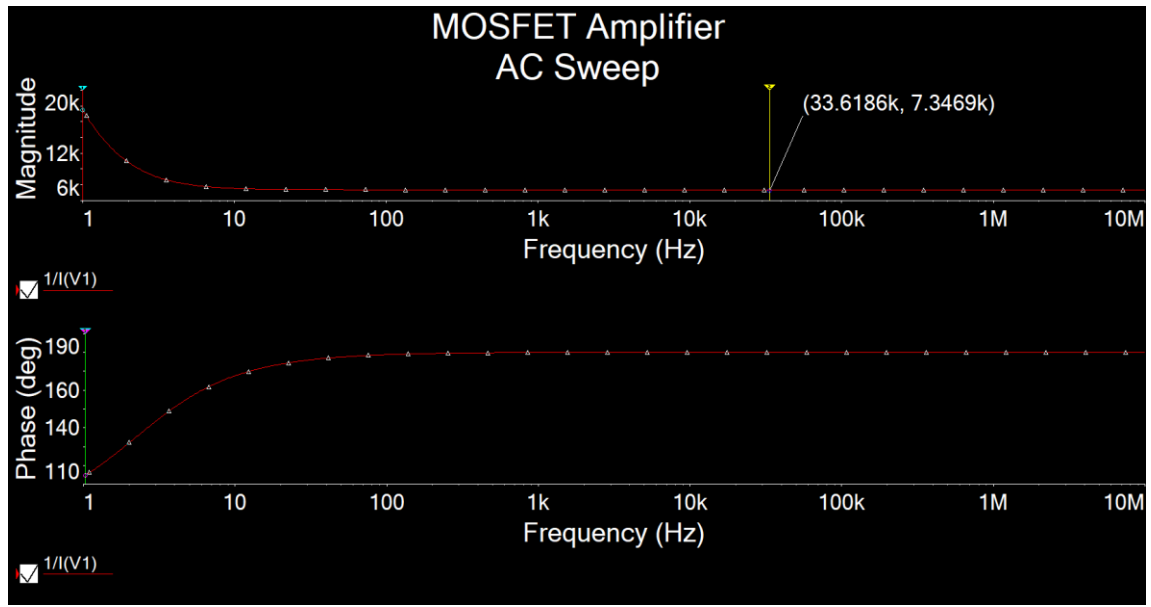
**Figure 1.1:** New circuit for MOSFET amplifier ▲



**Figure 2.1:** AC Simulation of  $A_v$  for MOSFET amplifier ▲

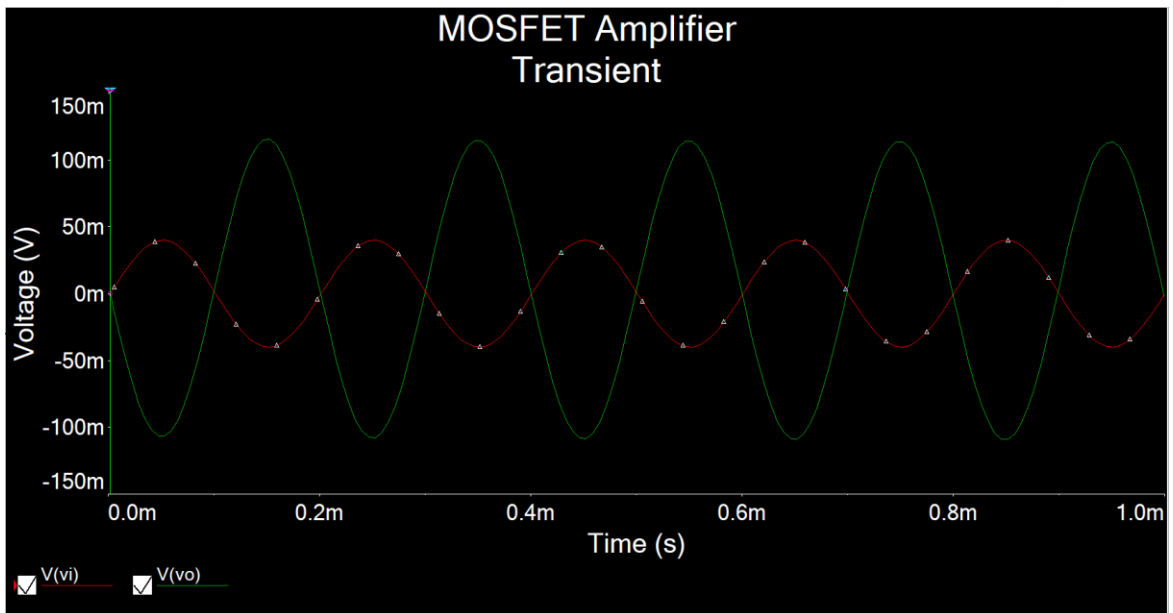
$$A_v = 2.8033$$

Even I rework the circuit, the best gain I can get is 2.8033.



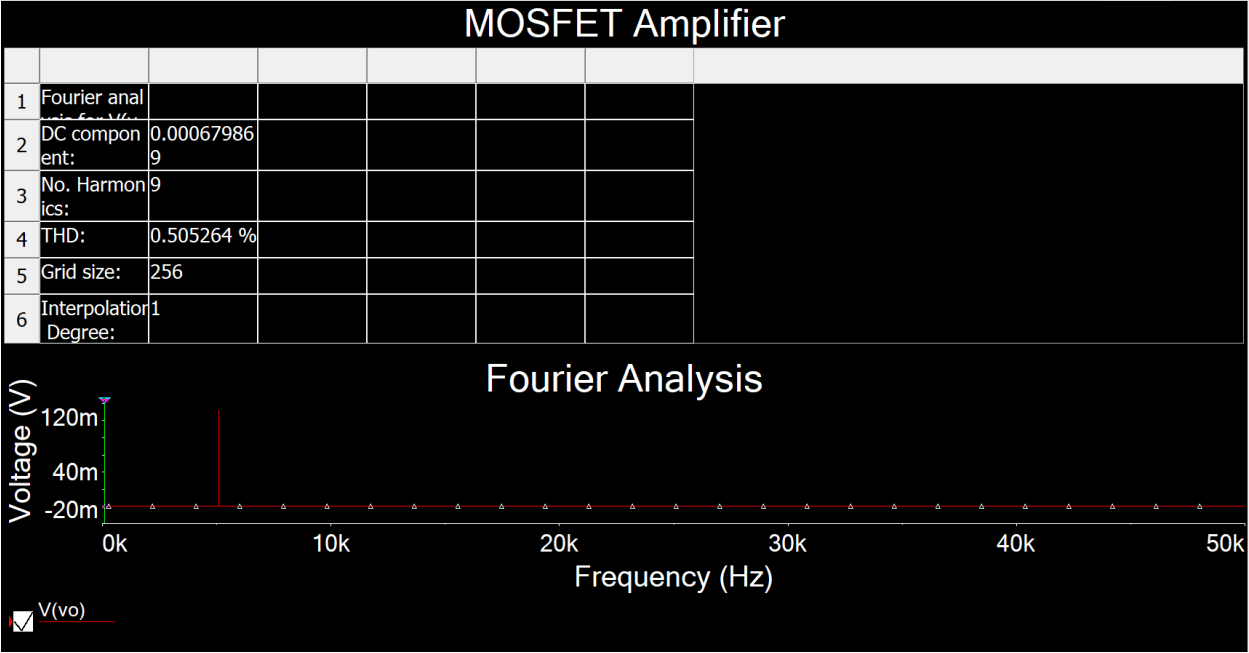
**Figure 2.2:** AC Simulation of  $R_i$  for MOSFET amplifier ▲

$$R_i = 7.3469k\Omega$$



**Figure 3:** Time-domain waveform of  $V_i = 40mV$  5kHz for MOSFET amplifier ▲

$$A_v \approx 2$$



**Figure 4:** Total harmonic distortion (THD) for MOSFET amplifier ▲

THD = 0.5053%